

Silicon PNP Power Transistors

2SB817

DESCRIPTION

- With TO-3PN package
- Complement to type 2SD1047

APPLICATIONS

- 140V/12A AF 60W output applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

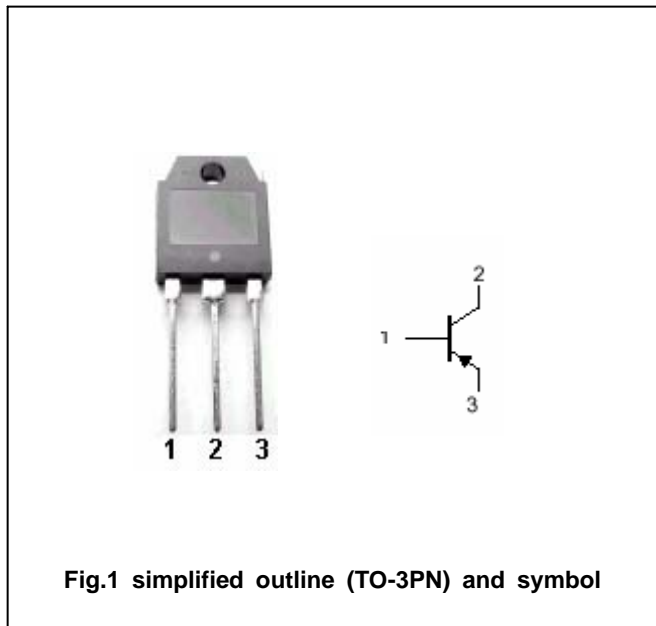


Fig.1 simplified outline (TO-3PN) and symbol

Absolute maximum ratings(Tc=25)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V _{CBO}	Collector-base voltage	Open emitter	-160	V
V _{CEO}	Collector-emitter voltage	Open base	-140	V
V _{EBO}	Emitter-base voltage	Open collector	-6	V
I _C	Collector current (DC)		-12	A
I _{CM}	Collector current-peak		-15	A
P _C	Collector power dissipation	T _C =25	100	W
T _j	Junction temperature		150	
T _{stg}	Storage temperature		-40~150	

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CHARACTERISTICS

T_j=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C =-50mA ; I _B =0	-140			V
V _{(BR)CBO}	Collector-base breakdown voltage	I _C =-5mA ; I _E =0	-160			V
V _{(BR)EBO}	Emitter-base breakdown voltage	I _E =-5mA ; I _C =0	-6			V
V _{CEsat}	Collector-emitter saturation voltage	I _C =-5A ; I _B =-0.5A		-1.1		V
V _{BE}	Base-emitter on voltage	I _C =-1A ; V _{CE} =-5V			-1.5	V
I _{CBO}	Collector cut-off current	V _{CB} =-80V ; I _E =0			-0.1	mA
I _{EBO}	Emitter cut-off current	V _{EB} =-4V ; I _C =0			-0.1	mA
h _{FE-1}	DC current gain	I _C =-1A ; V _{CE} =-5V	60		200	
h _{FE-2}	DC current gain	I _C =-6A ; V _{CE} =-5V	20			
f _T	Transition frequency	I _C =-1A ; V _{CE} =-5V		15		MHz
C _{OB}	Collector output capacitance	I _E =0 ; f=1MHz ; V _{CB} =10V		300		pF

Switching times

t _{on}	Turn-on time	I _C =-1.0A I _{B1} =-I _{B2} =-0.1A		0.25		μs
t _{stg}	Storage time			1.61		μs
t _f	Fall time			0.53		μs

◆ h_{FE-1} Classifications

D	E
60-120	100-200

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PACKAGE OUTLINE

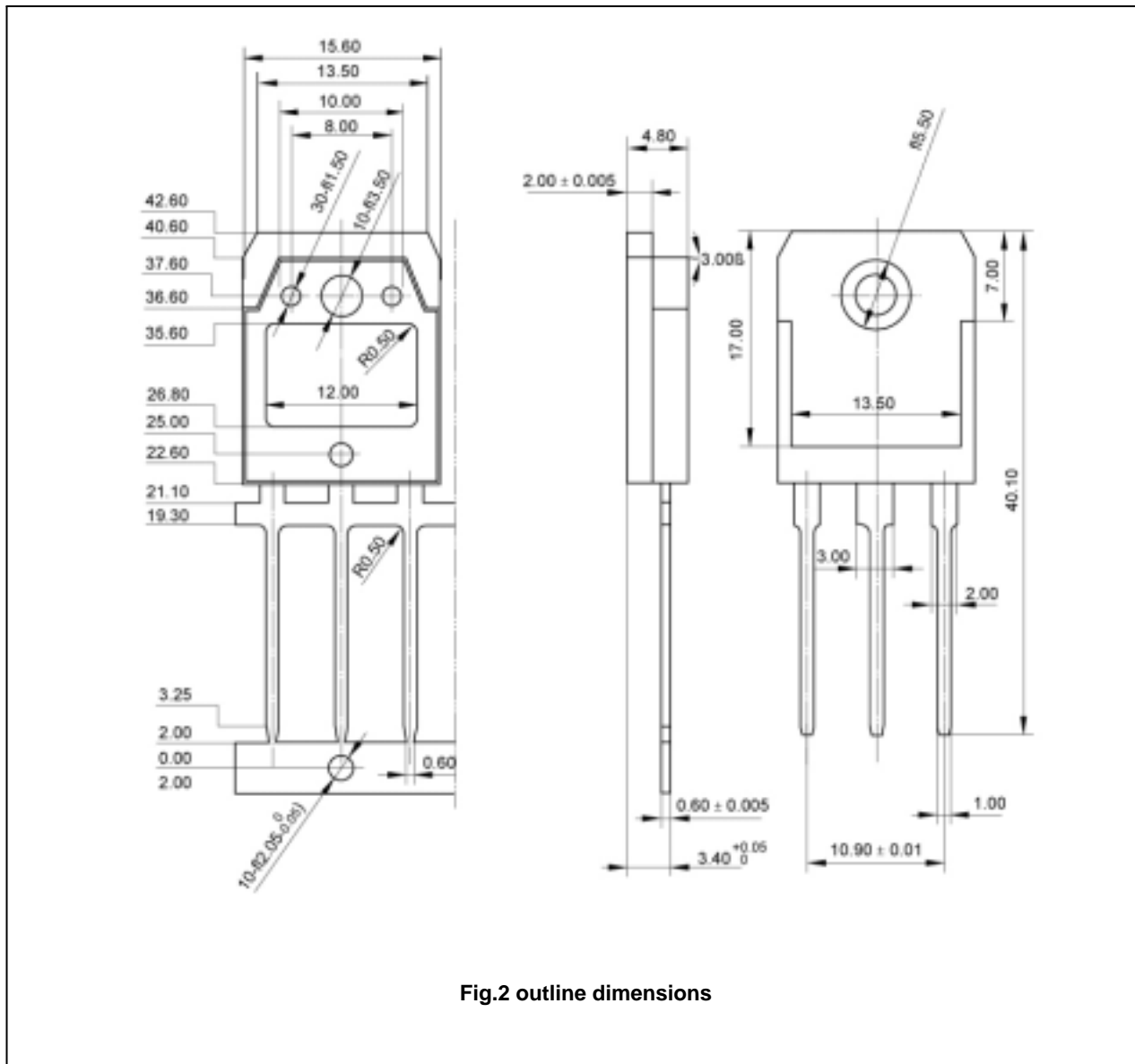


Fig.2 outline dimensions

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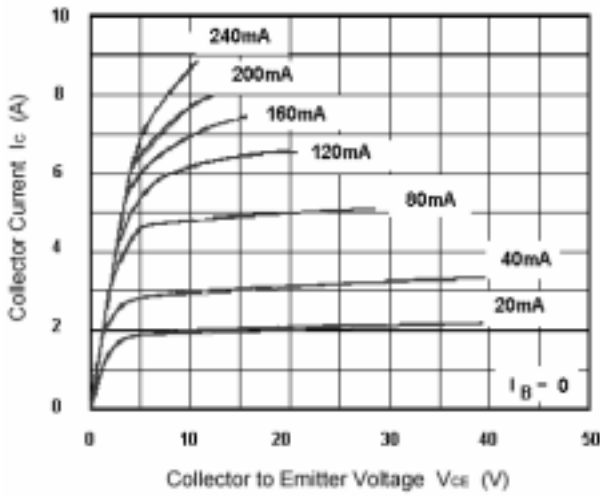


Fig.3 Static Characteristic

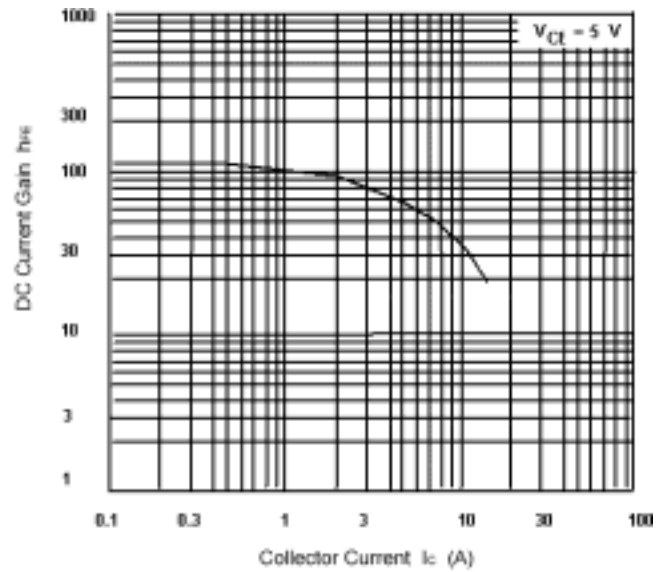


Fig.4 DC current Gain

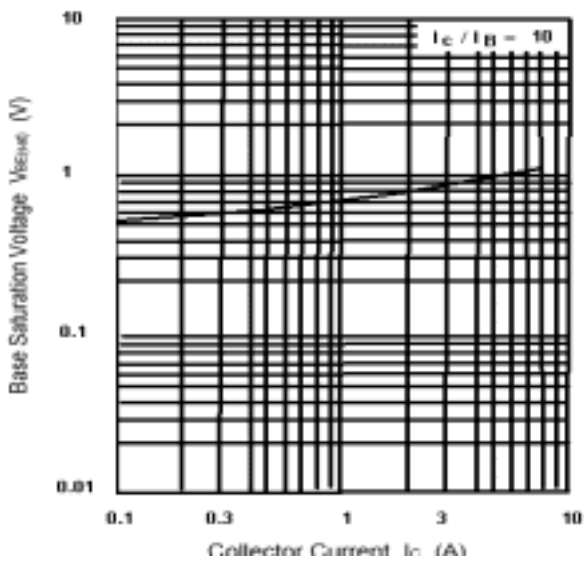


Fig.5 Base-Emitter Saturation Voltage

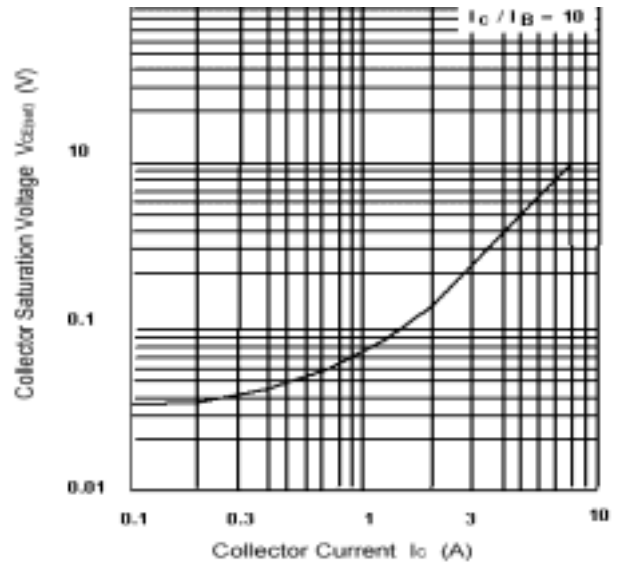


Fig.6 Collector-Emitter Saturation Voltage

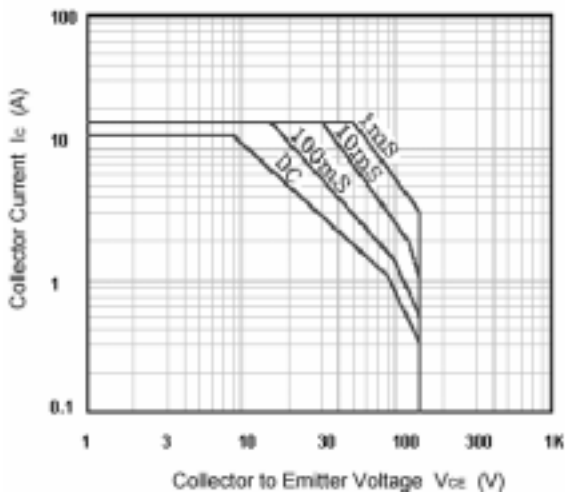


Fig.7 Safe Operating Area